

# **General Description**

The 8205A is the highest performance trench

N-ch MOSFETs with extreme high cell density, which provide excellent RDSON and gate charge

for most of the small power switching and

load  $\,$  switch applications. The meet the RoHS and

Product requirement with full function reliability approved.



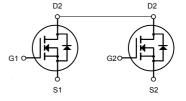
TSSOP-8

#### **General Features**

 $V_{DS} = 20V I_{D} = 6A$ 

 $R_{DS(ON)}$  < 27m $\Omega$  @  $V_{GS}$ =4. 5V

 $R_{DS(ON)}$  <37m $\Omega$  @  $V_{GS}$ =2. 5V



# **Application**

Battery protection

Load switch

Uninterruptible power supply

### **Dual N-Channel MOSFET**

# **Package Marking and Ordering Information**

| Product ID | Pack    | Marking | Qty(PCS) |
|------------|---------|---------|----------|
| 8205A      | TSSOP-8 | 8205    | 5000     |

# Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

| Symbol                           | Parameter  | Limit      | Unit       |  |
|----------------------------------|--|------------|------------|--|
| V <sub>DS</sub>                  | Drain-Source Voltage                             | 20         | V          |  |
| Vgs                              | Gate-Source Voltage                              | ±12        | V          |  |
| I <sub>D</sub>                   | Drain Current-Continuous                         | 6          | А          |  |
| Ірм                              | Drain Current-Pulsed (Note 1)                    | 25         | А          |  |
| P <sub>D</sub>                   | Maximum Power Dissipation                        | 1.5        | W          |  |
| T <sub>J</sub> ,T <sub>STG</sub> | Operating Junction and Storage Temperature Range | -55 To 150 | $^{\circ}$ |  |
| Reja                             | Thermal Resistance,Junction-to-Ambient (Note 2)  | 83         | °C/W       |  |



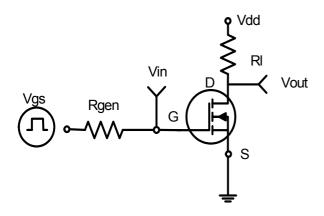
# Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)

| Parameter                        | Symbol              | Condition  | Min | Тур  | Max  | Unit |
|----------------------------------|---------------------|--|-----|------|------|------|
| Drain-Source Breakdown Voltage   | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250µA                | 20  | 21   | -    | ٧    |
| Zero Gate Voltage Drain Current  | Ipss                | V <sub>DS</sub> =19.5V,V <sub>GS</sub> =0V               | -   | -    | 1    | μA   |
| Gate-Body Leakage Current        | lgss                | V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V                | -   | _    | ±100 | nA   |
| Gate Threshold Voltage           | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA  | 0.5 | 0.7  | 1.2  | V    |
|                                  | Rds(on)             | V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A              | -   | 21   | 27   | mΩ   |
| Drain-Source On-State Resistance |                     | V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.5A              | -   | 27   | 37   | mΩ   |
| Forward Transconductance         | grs                 | V <sub>DS</sub> =5V,I <sub>D</sub> =4.5A                 | -   | 10   | -    | S    |
| Input Capacitance                | C <sub>lss</sub>    |  | -   | 600  | -    | PF   |
| Output Capacitance               | Coss                | V <sub>DS</sub> =8V,V <sub>GS</sub> =0V,<br>F=1.0MHz     | -   | 330  | -    | PF   |
| Reverse Transfer Capacitance     | Crss                | F-1.UIVIDZ   | -   | 140  | -    | PF   |
| Turn-on Delay Time               | td(on)              |  | -   | 10   | 20   | nS   |
| Turn-on Rise Time                | tr                  | V <sub>DD</sub> =10V,I <sub>D</sub> =1A                  | -   | 11   | 25   | nS   |
| Turn-Off Delay Time              | td(off)             | $V_{GS}=10V, N_{GEN}=12V$ $V_{GS}=4.5V, R_{GEN}=6\Omega$ | -   | 35   | 70   | nS   |
| Turn-Off Fall Time               | t <sub>f</sub>      |  | -   | 30   | 60   | nS   |
| Total Gate Charge                | Qg                  |  | -   | 10   | 15   | nC   |
| Gate-Source Charge               | Qgs                 | V <sub>DS</sub> =10V,I <sub>D</sub> =6A,                 | -   | 2.3  | -    | nC   |
| Gate-Drain Charge                | Q <sub>gd</sub>     | V <sub>GS</sub> =4.5V                                    | -   | 1.5  | -    | nC   |
| Diode Forward Voltage (Note 3)   | VsD                 | V <sub>GS</sub> =0V,I <sub>S</sub> =1.7A                 | -   | 0.75 | 1.2  | V    |
| Diode Forward Current (Note 2)   | Is                  |  | -   | -    | 1.7  | Α    |

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

# **Typical Characteristics**



**Figure 1:Switching Test Circuit** 

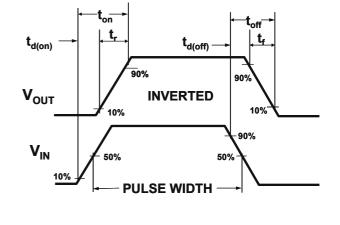
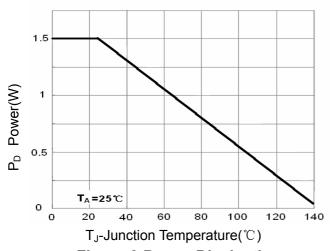
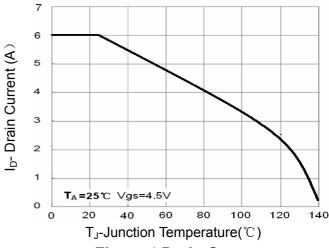


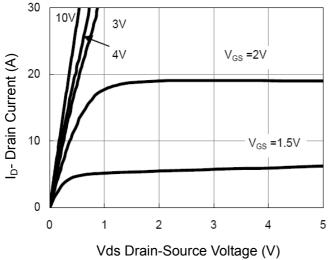
Figure 2:Switching Waveforms



**Figure 3 Power Dissipation** 



**Figure 4 Drain Current** 



**Figure 5 Output Characteristics** 

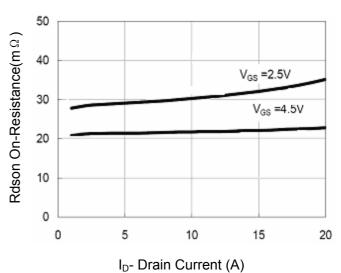
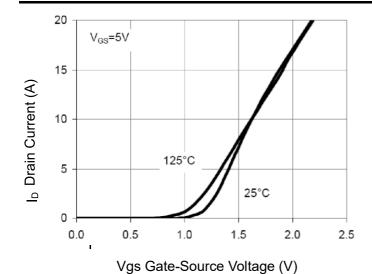
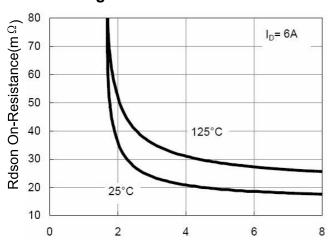


Figure 6 Drain-Source On-Resistance



**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V) Figure 9 Rdson vs Vgs

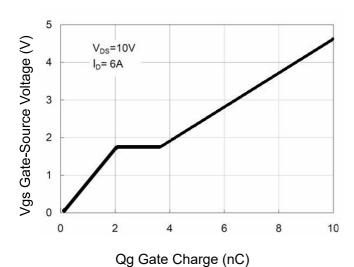
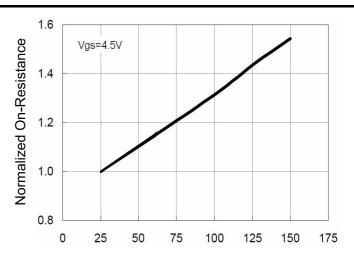
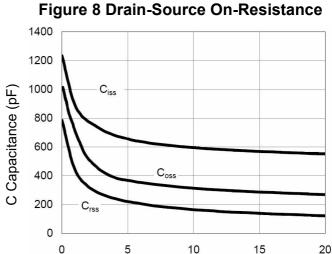


Figure 11 Gate Charge

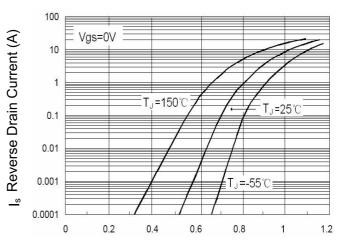


T<sub>J</sub>-Junction Temperature(℃)



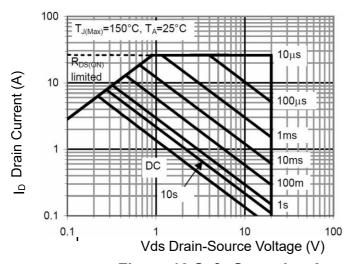
Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds

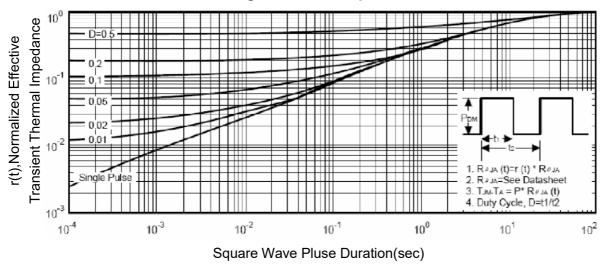


Vsd Source-Drain Voltage (V)

Figure 12 Source- Drain Diode Forward



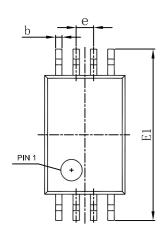
**Figure 13 Safe Operation Area** 

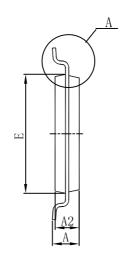


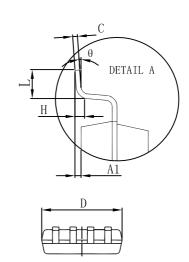
**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **TSSOP-8 Package Outline Dimensions**







| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |        |  |
|--------|---------------------------|--------|----------------------|--------|--|
|        | Min                       | Max    | Min                  | Max    |  |
| D      | 2.900                     | 3. 100 | 0. 114               | 0. 122 |  |
| Е      | 4.300                     | 4. 500 | 0. 169               | 0.177  |  |
| b      | 0.190                     | 0.300  | 0.007                | 0.012  |  |
| c      | 0.090                     | 0.200  | 0.004                | 0.008  |  |
| E1     | 6.250                     | 6. 550 | 0. 246               | 0.258  |  |
| A      |                           | 1. 200 |                      | 0.047  |  |
| A2     | 0.800                     | 1.000  | 0.031                | 0.039  |  |
| A1     | 0.050                     | 0. 150 | 0.002                | 0.006  |  |
| e      | 0.65 (BSC)                |        | 0. 026 (BSC)         |        |  |
| L      | 0.500                     | 0.700  | 0.020                | 0.028  |  |
| Н      | 0.25(TYP)                 |        | 0.01(TYP)            |        |  |
| θ      | 1°                        | 7°     | 1°                   | 7°     |  |



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